## NSN 5961-01-187-0543

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## Inclosure Material:

Metal

**Overall Length:** 

0.935 inches

## Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-60

## Electrode Internally-electrically Connected To Case:

Anode

**Mounting Method:** 

Threaded stud

#### Features Provided:

Hermetically sealed case

## **Overall Width Across Flats:**

0.437 inches

## Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

55.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 3.5 emitter to

base voltage, static, collector open

## **Current Rating Per Characteristic:**

Between 400.00 milliamperes source cutoff current and 400.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

4.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

3 uninsulated wire lead and 1 threaded stud

#### Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

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